

#### Standard 1A Triacs

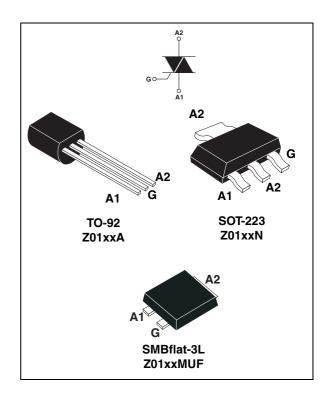
#### **Features**

- On-state rms current, I<sub>T(RMS)</sub> 1 A
- Repetitive peak off-state voltage, V<sub>DRM</sub>/V<sub>RRM</sub> 600 or 800 V
- Triggering gate current, I<sub>GT (Q1)</sub> 3 to 25 mA

#### **Description**

The Z01 series is suitable for general purpose AC switching applications. These devices are typically used in applications such as home appliances (electrovalve, pump, door lock, small lamp control), fan speed controllers,...

Different gate current sensitivities are available, allowing optimized performance when driven directly through microcontrollers.



Characteristics Z01

## 1 Characteristics

Table 1. Absolute maximum ratings

Symbol	Parameter	Value	Unit			
		SOT-223	T <sub>tab</sub> = 90 °C			
I <sub>T(RMS)</sub>	On-state rms current (full sine wave)	TO-92	T <sub>L</sub> = 50 °C	1	Α	
		SMBflat-3L	T <sub>tab</sub> = 107 °C			
1	Non repetitive surge peak on-state	F = 50 Hz	t = 20 ms	8	Α	
I <sub>TSM</sub>	current (full cycle, T <sub>j</sub> initial = 25 °C)	F = 60 Hz	t = 16.7 ms	8.5		
l <sup>2</sup> t	$t_p = 10 \text{ ms}$		0.35	A <sup>2</sup> s		
dl/dt	Critical rate of rise of on-state current $I_G = 2 \times I_{GT}$ , $t_r \le 100 \text{ ns}$	F = 120 Hz	T <sub>j</sub> = 125 °C	20	A/μs	
I <sub>GM</sub>	Peak gate current $t_p = 20 \mu s$		T <sub>j</sub> = 125 °C	1	Α	
P <sub>G(AV)</sub>	Average gate power dissipation	T <sub>j</sub> = 125 °C	1	W		
T <sub>stg</sub> T <sub>j</sub>	Storage junction temperature range Operating junction temperature range	- 40 to + 150 - 40 to + 125	°C			

Table 2. Electrical characteristics ( $T_j = 25$  °C, unless otherwise specified)

Symbol	Test conditions	Quadrant			Z	01		Unit
Cymbol	rest conditions	Quaurant		03	07	09	10	Offic
In- (1)	V 40.V	1 - 11 - 111	MAX.	3	5	10	25	mA
GI	$V_D = 12 V$ , $R_1 = 30 \Omega$	IV	IVI/A/X.	5	7	10	25	111/3
$V_{GT}$	L	ALL	MAX.		1.	.3		V
$V_{GD}$	$\begin{aligned} &V_D = V_{DRM}, \\ &R_L = 3.3 \text{ k}\Omega, \\ &T_j = 125 \text{ °C} \end{aligned} \qquad \text{ALL}$		MIN.	0.2				V
I <sub>H</sub> (2)	I <sub>T</sub> = 50 mA		MAX.	7	10	10	25	mA
,	-    -  V	I - III - IV	MAX.	7	10	15	25	mA
IL	$I_{G} = 1.2 I_{GT}$	II	IVIAA.	15	20	25	50	IIIA
dV/dt (2)	$V_D = 67\% V_{DRM}$ gate open $T_j = 110 ^{\circ}\text{C}$		MIN.	10	20	50	100	V/µs
	$(dI/dt)_{c} = 0.44 \text{ A/m}$ $T_{j} = 110 ^{\circ}\text{C}$	$(dI/dt)_{c} = 0.44 \text{ A/ms},$ $T_{j} = 110 ^{\circ}\text{C}$		0.5	1	2	5	V/µs

<sup>1.</sup> Minimum  $I_{\mbox{\scriptsize GT}}$  is guaranteed at 5% of  $I_{\mbox{\scriptsize GT}}$  max.

<sup>2.</sup> For both polarities of A2 referenced to A1.

Z01 Characteristics

Table 3. Static characteristics

Symbol	Test conditions	Value	Unit		
V <sub>TM</sub> <sup>(1)</sup>	$I_{TM} = 1.4 \text{ A}, t_p = 380 \ \mu \text{s}$	T <sub>j</sub> = 25 °C	MAX.	1.6	V
V <sub>to</sub> <sup>(1)</sup>	Threshold voltage	T <sub>j</sub> = 125 °C	MAX.	0.95	V
R <sub>d</sub> <sup>(1)</sup>	Dynamic resistance	T <sub>j</sub> = 125 °C	MAX.	400	mΩ
I <sub>DRM</sub>	VV	T <sub>j</sub> = 25 °C MAX.		5	μΑ
I <sub>RRM</sub>	$V_{DRM} = V_{RRM}$	T <sub>j</sub> = 125 °C	IVIAA.	0.5	mA

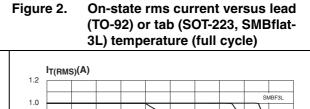
<sup>1.</sup> For both polarities of A2 referenced to A1.

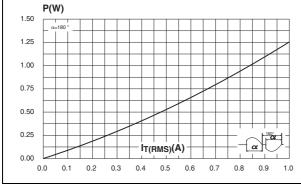
Table 4. Thermal resistances

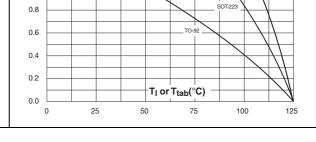
Symbol		Value	Unit			
R <sub>th(j-t)</sub>	Junction to tab (AC)		SOT-223		25	
R <sub>th(j-t)</sub>	Junction to tab (AC)		SMBflat-3L		14	
R <sub>th(j-l)</sub>	Junction to lead (AC)		TO-92	MAX.	60	°C/W
		$S^{(1)} = 5 \text{ cm}^2$	SOT-223	IVIAA.	60	C/VV
R <sub>th(j-a)</sub>	Junction to ambient	3. 7 = 3 CIII	SMBflat-3L		75	
			TO-92		150	

<sup>1.</sup> S = copper surface under tab.

Figure 1. Maximum power dissipation versus on-state rms current (full cycle)



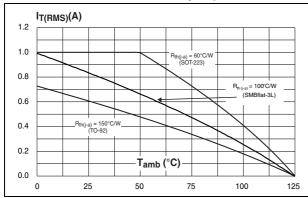




Characteristics Z01

Figure 3. On-state rms current versus ambient temperature (free air convection full cycle)

Figure 4. Relative variation of thermal impedance versus pulse duration (Z<sub>th(j-a)</sub>)



1.00 K=[Zth(j-a)/Rth(j-a)]

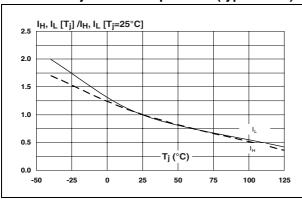
0.10

0.10

1.0E-03 1.0E-02 1.0E-01 1.0E+00 1.0E+01 1.0E+02 1.0E+03

Figure 5. Relative variation of holding current and latching current versus junction temperature (typ. values)

Figure 6. Relative variation of gate trigger current (I<sub>GT</sub>) and voltage (V<sub>GT</sub>) versus junction temperature



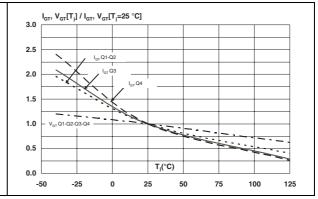
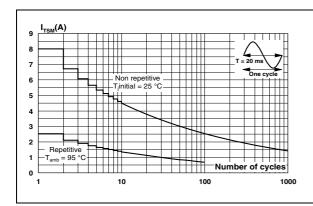
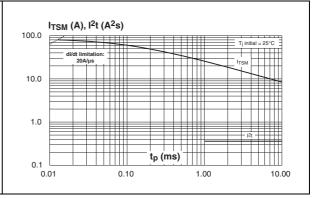


Figure 7. Surge peak on-state current versus Figure 8. number of cycles

Non-repetitive surge peak on-state current and corresponding value of I<sup>2</sup>t sinusoidal pulse width





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**Z**01 **Characteristics** 

Figure 9. **On-state characteristics** (maximum values)  $(I_{TM} = f(V_{TM})$ 

Figure 10. Relative variation of critical rate of decrease of main current versus  $(dV/dt)_c$ 

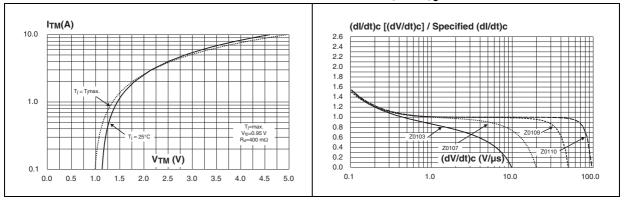


Figure 11. decrease of main current (dl/dt) versus junction temperature

Relative variation of critical rate of Figure 12. SOT-223 and SMBflat-3L thermal resistance junction to ambient versus copper surface under case

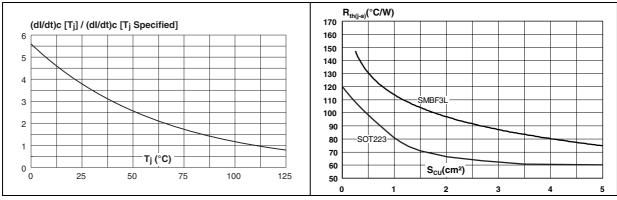
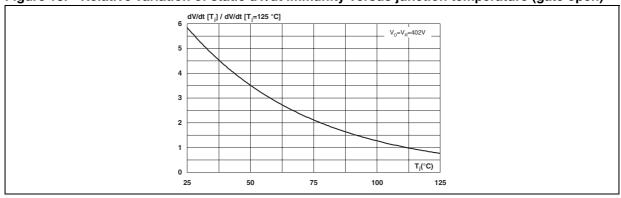


Figure 13. Relative variation of static dV/dt immunity versus junction temperature (gate open)



## 2 Ordering information scheme

Figure 14. Ordering information scheme

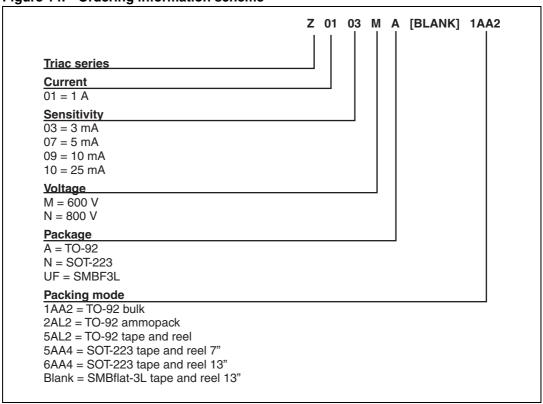


Table 5. Product Selector

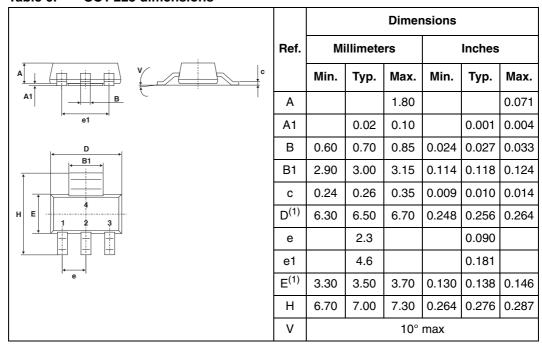
Oudou oo do	Volt	tage	Concitivity	Turne	Doolsono	
Order code	600 V	800 V	Sensitivity	Туре	Package	
Z0103MA	Х		3 mA	Standard	TO-92	
Z0103MN	Х		3 mA	Standard	SOT-223	
Z0103NA		Х	3 mA	Standard	TO-92	
Z0103NN		Х	3 mA	Standard	SOT-223	
Z0107MA	Х		5 mA	Standard	TO-92	
Z0107MN	Х		5 mA	Standard	SOT-223	
Z0107NA		Х	5 mA	Standard	TO-92	
Z0107NN		Х	5 mA	Standard	SOT-223	
Z0109MA	Х		10 mA	Standard	TO-92	
Z0109MN	Х		10 mA	Standard	SOT-223	
Z0109NA		Х	10 mA	Standard	TO-92	
Z0109NN		Х	10 mA	Standard	SOT-223	
Z0110MA	Х		25 mA	Standard	TO-92	
Z0110MN	Х		25 mA	Standard	SOT-223	
Z0110NA		Х	25 mA	Standard	TO-92	
Z0110NN		Х	25 mA	Standard	SOT-223	
Z0103MUF	Х		3 mA	Standard	SMBflat-3L	
Z0107MUF	Х		5 mA	Standard	SMBflat-3L	
Z0109MUF	Х		10 mA	Standard	SMBflat-3L	

### 3 Packaging information

- Epoxy meets UL94, V0
- Lead-free packages

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK<sup>®</sup> packages, depending on their level of environmental compliance. ECOPACK<sup>®</sup> specifications, grade definitions and product status are available at: <a href="www.st.com">www.st.com</a>. ECOPACK<sup>®</sup> is an ST trademark.

Table 6. SOT-223 dimensions



 $<sup>1. \</sup>quad \text{Do not include mold flash or protrusions. Mold flash or protrusions shall not exceed 0.15 mm (0.006 inches)}\\$ 

Figure 15. SOT-223 footprint dimensions (in millimeters)

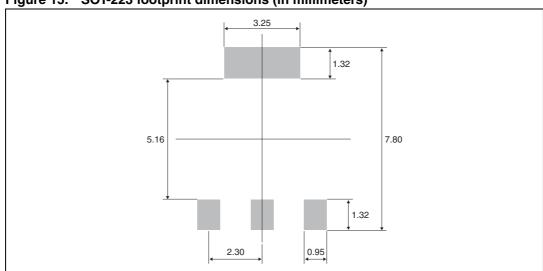
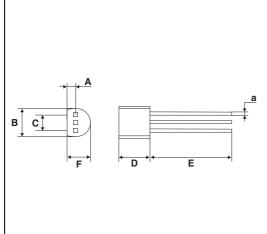
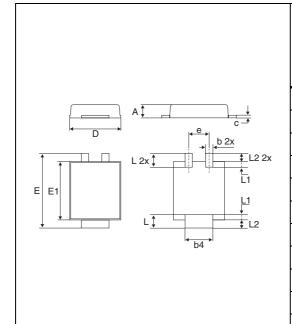


Table 7. TO-92 dimensions



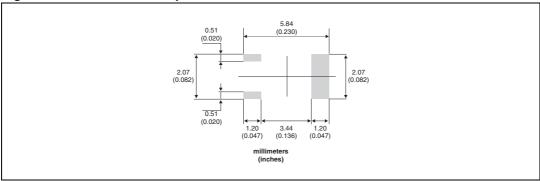
	Dimensions					
REF.	Mi	Millimeters Inch			Inches	
	Min.	Тур.	Max.	Min.	Тур.	Max.
Α		1.35			0.053	
В			4.70			0.185
С		2.54			0.100	
D	4.40			0.173		
Е	12.70			0.500		
F			3.70			0.146
а			0.50			0.019

Table 8. SMBflat-3L dimensions



	Dimensions									
Ref.	f. Millim		ers							
	Min.	Тур.	Max.	Min.	Тур.	Max.				
Α	0.90		1.10	0.035		0.043				
b	0.35		0.65	0.014		0.026				
b4	1.95		2.20	0.07		0.087				
С	0.15		0.40	0.006		0.016				
D	3.30		3.95	0.130		0.156				
Е	5.10		5.60	0.201		0.220				
E1	4.05		4.60	0.156		0.181				
L	0.75		1.50	0.030		0.059				
L1		0.40			0.016					
L2		0.60			0.024					
е		1.60			0.063					

Figure 16. SMBflat-3L footprint dimensions



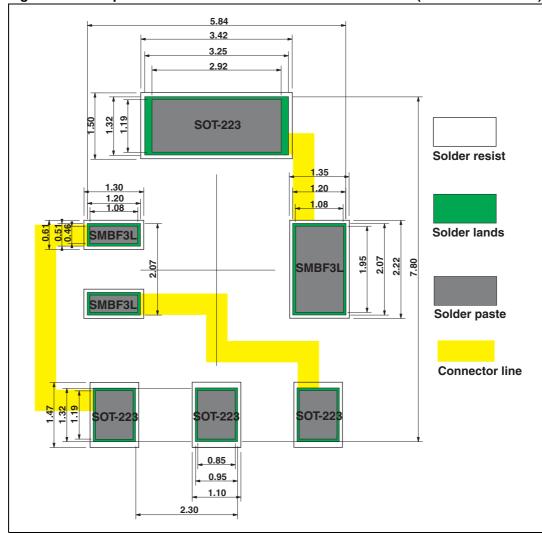


Figure 17. Footprint and connectors for SOT-223 or SMBflat-3L (dimensions in mm)

# 4 Ordering information

Table 9. Ordering information

Order code <sup>(1)</sup>	Marking <sup>(1)</sup>	Package	Weight	Base quantity	Delivery mode
Z01xxyA 1AA2	Z01xxyA	TO-92	0.2 g	2500	Bulk
Z01xxyA 2AL2	Z01xxyA	TO-92	0.2 g	2000	Ammopack
Z01xxyA 5AL2	Z01xxyA	TO-92	0.2 g	2000	Tape and reel
Z0103yN 5AA4	Z3y	SOT-223	0.12 g	1000	Tape and reel
Z0107yN 5AA4	Z7y	SOT-223	0.12 g	1000	Tape and reel
Z0109yN 5AA4	Z9y	SOT-223	0.12 g	1000	Tape and reel
Z0103MUF	Z3M	SMBflat-3L	46.78 mg	5000	Tape and reel
Z0107MUF	Z7M	SMBflat-3L	46.78 mg	5000	Tape and reel
Z0109MUF	Z9M	SMBflat-3L	46.78 mg	5000	Tape and reel

<sup>1.</sup> xx = sensitivity, y = voltage

## 5 Revision history

Table 10. Document revision history

Date	Revision	Changes
Oct-2001	4	Last update.
10-Feb-2005	5	Package: TO-92 tape and reel delivery mode 5AL2 added.
09-May-2005	6	Table 4 on page 2: typo. mistake corrected  1. (dV/dt)c instead of (dl/dt)c  2. V/µs unit instead of A/ms
21-Apr-2006	7	Reformatted to current standard. Table 2 on page 2: Typo corrected. Values for I <sub>GT</sub> split into two separate rows.
10-Oct-2006	8	Table 2: modified test conditions for $(dV/dt)_{c.}$ Changed "ambient" to "lead or tab" in Figure 2.
20-Oct-2010	9	Package: SOT-223 13" tape and reel added = 6AA4
14-Dec-2010	10	Added package SMBflat-3L. Updated dimensions in <i>Table 6</i> . Updated <i>Figure 3</i> and <i>Figure 12</i> . Updated <i>Table 5: Product Selector</i> .

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